NSN 5962-00-328-0038

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View Online at https://aerobasegroup.com/nsn/5962-00-328-0038
Body Length:
Between 0.370 inches and 0.395 inches
Body Width:
Between 0.240 inches and 0.260 inches
Body Height:
Between 0.050 inches and 0.085 inches
Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and expandable and w/buffered output and wire-or outputs and bipolar
and programmable and programmed and w/decoded output
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
3 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
25.00 nanoseconds propagation delay time, low to high level output and 75.00 nanoseconds propagation delay time, low to high level
putput
Memory Device Type:
Rom
Memory Capacity:
Unknown
Test Data Document:
82577-932085 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
Memory Capacity: Unknown Test Data Document:

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Unit Of Measure:

24 flat leads Shelf Life:

Terminal Type And Quantity:

N/a

Demilitarization: Voc. domil/mli

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